

ESSCIRC/ESSDERC 2023 SiNANO-ICOS Workshop "European Strengths and Gaps in Emerging Semiconductor Technologies"

Energy Harvesting: review of the main EU and international activities and technologies

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Outline



Introduction

- Energy harvesting technologies (IEEE-IRDS)
 - Main technologies, trends, challenges, examples
 - Most active universities / RTO
- Conclusions and perspectives







INTRODUCTION

Introduction



- Market growth on connected devices : IoT (estimated 40 billion devices by 2025), healthcare, wearables, home automation...
- \Box Energy supply is essential (<mW, tens of μ W) \longrightarrow Energy Harvesting
- EH is important in applications with specific requirements : simple battery is not enough, cords would increase the cost / complexity, too many devices, harsh environment, implants...





Introduction: Technologies covered so far...





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Energy harvesting technologies



- Harvesting principle based on mechanical resonators
- Applications are linked to mechanical vibrations harvesting (movements)



• Principle

Resonant cantilever covered by a piezoelectric layer and a inertial mass attached. As the cantilever is bent, strain is transferred to the piezo layer — asymmetric charge distribution (Voltage) MIDE (PZT)

- Devices tuned at a specific vibration frequency
- Devices are easy to fabricate
- Macro-devices and MEMS are actually on the market
- □ Most used materials (commercial) : PZT (lead/toxic), PVDF



TE Connectivity

(PVDF)

Mechanical EH : Piezoelectric conversion



- Current trends:
- □ Increase input bandwidth / reduce working frequency for portable applications
- □ Frequency-up converter (rotating systems)



Mechanical EH : Electrostatic conversion





Principle

One electrode of the capacitor is charged (electret, triboelectricity...) and the relative movement between the two electrodes causes a variation of electric capacity \longrightarrow charges movement

- Energy density is low at macro level but increases at micro scale (relative capacitor variation increases)
- □ Main challenge is related to the reliability of the material to keep the charges



Mechanical EH : Electrostatic conversion



- Current trends:
- □ MEMS device Increase input bandwidth
- □ impact frequency up converter (stoppers & balls)







• Principle: Faraday's Law

Relative motion – magnetic field & coil (or change in the flux linkage) — Electromotive force

- Macro-devices are vastly developed and are on the market
- MEMS devices less explored due to drastic drop in performance
- □ Use of rare earth-based magnetic NdFeB





Perpetuum 68 mm x 63 mm P < 20mW

Enocean 29 x 19 x 7 mm³ 200µJ@2V





- Current trends:
- Increase input bandwidth Exploiting non-linearities (springs)







Thermal EH





• Principle

<u>Seebeck effect</u>: generation of a voltage along a conductor when it is subjected to a temperature difference.

Main parameter : $zT=\sigma S^2T/\kappa$. σ : electrical conductivity (1/ Ω /m), S : Seebeck coefficient (V/K), κ : thermal conductivity (W/m/K), T : temperature (K).

 $zT \sim 1 (now) \longrightarrow 3 (future)$

- □ Fast thermalization (need for a big heat sink)
- □ Non-flexible
- Bi₂Te₃ : Expensive/rare/toxic material/incompatible with CMOS
- Power proportional to available temperature gradient



Micropelt ~4 x 3 X 1 mm P < 15mW @ ΔT=30K

Nextreme ~ 11 x 10 x 1 mm P < 130mW @ ΔT=50K



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Thermal EH



- □ Current trends:
- □ Enhancement of the coupling to environmental heat source at system level.
- Dynamic thermoelectric energy harvesting (heat storage)



Thermal EH: Most active universities / RTO





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Photovoltaic EH





Principle : Photovoltaic effect:

- Absorption of light by the semiconductor Electron-hole pair generation,
- separation and collection \longrightarrow Power delivered



a-Si, organic, DSSC (dye sensitized solar cells), semiconductors compounds (III-V, CdTe,...), Perovskite

Si, tandem cells on Si, semiconductors compounds (CIGS...)

Courtesy of A. Kaminski, NEREID, 2016.



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- A market dominated by the Si (mature technology):
 - For outdoor applications, crystalline Si solar cells
 - For indoor applications, amorphous Si photovoltaic cells
- Solar cells spectral sensitivity and efficiency differ depending on the light spectrum which is very different for artificial and sun light



Photovoltaic EH: current trends



- Develop high efficiency and low cost transparent PV (flexible, even better)
- PV covering other things other than roofs (e.g. windows, walls, e-devices ...)
- □ Not all application need to be 100% transparent or highly efficient



- Still work to be done before reachning large scale: reduce losses, increase lifetime...
- Low resistivity transparent electrodes (Nanowires, nanotubes, thin metallic films)
 C. J. Traverse et al., Nature energy, 2017

SCSE ELECTRON EVICES SOCIETY IN ICON SINAN Institute European Institute

Photovoltaic EH: Most active universities / RTO



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RF EH /Wireless power transfer





2 Principles :

- Radiated far field RF source (High frequency 300MHz-GHz)
- -> Antennas (no interaction)
- Near EM field Capacitive or inductive coupling (low frequency 30kHz-MHz) ->coils, electrodes (strong interaction)
- □ Far field : Used for low/ultra low power (~µW-mW)
 - Applications (harvesting)
 - Low efficiency
 - No commercial applications
- □ Near Field : medium to high power app. (\sim mW-W-kW).
 - Medium to high efficiency
 - Commercial applications



RF EH/wireless power transfer: current trends

- \Box EH at mm wave : how to reach high gains + wide angular coverage (RF to DC)
- □ Typically Low power transmitted (regulations) \longrightarrow 5G (higher power)! > 24GHz

Beamforming networks (BFNs) Rotman lens







- It channels energy coming from any direction to one of the rectifiers.
- Stable output regardless of the sources location (RF source location is unknown)
- Increase in power (same angular coverage w/o BF)

A. Eid et al., IEEE/MMT Symposium, 2019





RF EH/wireless power transfer : Most active universities / RTO







Energy storage: Micro-batteries





Principle :

- Electrolyte : high ion conductivity, low electronic

10μm conductivity

- Replacement of the classical
- liquide electrolyte \longrightarrow thin film
- Si integrated
- Size reduction, safer
- □ Lithium based thin films: \sim 1 mWh/cm², capacity retention -> 1000 cycles
- □ Electrode thickness limit < \sim µm
- □ Ionic conductivity of solid elecrolyte << liquid based (commercial)
- Thin film solid-state solutions for energy storage have existed for some years now but more energy density and higher power options at lower cost are required



Energy storage: Micro-batteries – current trends

Increase of performances : new materials for electrodes (quality), electrolyte
 Electrodes protective layers: Lithium cobalt oxide / Al₂O₃, Si / C



Energy storage: Micro-batteries - Most active universities / RTO







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Micro-power management





A. Romani et al., Computer, 2017

- Essential to store and deliver the harvested energy to circuits
- Must consume less than the input power
- Efficiency must be traded with self-consumption
- Should keep sources in the MPP
- \Box It must be able to handle very low levels of ambient energies (1 μ W).
- □ It must also be able to operate with near-0 voltages.
- □ Major silicon foundries have proposed in recent years dedicated products operating down to few µW and few hundreds mV, along with very tiny implementations requiring few components



Micro-power management: current trends



- □ Size reduction, increase efficiency, multiple harvesters...
- □ Multiple EH + Batteries, multiple out-puts
- □ Single inductor (DC-DC) → size reduction
- $\Box \quad \text{One stage} \longrightarrow \text{reduce losses}$



- 28-nm FDSOI
- Die area 0.5 mm²
- Output power 1µW 60mW (efficiency >75%), Vout 1V
- Minimum input power 262nW

S. S. Amin et al., IEEE JSSC, 2018



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Micro-power management : Most active universities / RTO







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- The improvement of the EH performance/efficiency is as important as the development of "green" materials. Replacing toxic/rare materials used nowadays (lead based piezoelectrics, Bi₂Te₃ for thermoelectrics, NdFeB neodymium, for electromagnetic conversion).
- □ The use of nanotechnologies is foreseen to increase the performance of all the concepts in general.
- Flexible and low cost approaches for wearable applications (i.e. e-health) should be developed as well.
- The comprehensive system design combining all aspects of the fabrication process, harvester structure, power conversion circuits and storage will be the potential solution for increasing the power generation efficiency.







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International Roadmap for Devices and Systems MORE THAN MOORE WHITE PAPER

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Thank you for your attention !

